Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.875 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

1.057 inches

Thread Size:

6.0 millimeters

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

75.0 nonrepetitive peak reverse voltage, peak total value and 50.0 reverse voltage, peak

Current Rating Per Characteristic:

70.00 amperes forward current, total rms megahertz

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector outside diameter

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Test Data Document:

56232-338378 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

lso m

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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